TPS54202x 4.5V to 30V, 2A, EMI Friendly, Synchronous Step-Down Converter

<div style="writing-mode: vertical">**ADVANCE INFORMATION**</div>

1 Features

- Configured for a wide range of applications
  - 4.5V to 30V input voltage range
  - Selectable adjustable output (TPS542021), fixed 5V output (TPS542025)
  - Up to 2A continuous output current
  - 0.6V ± 1.5% reference voltage (25°C)
  - Supports low drop out mode
- High efficiency
  - Integrated 100mΩ and 60mΩ MOSFETs
  - Low 2µA shutdown, 26µA quiescent current
  - Pulse frequency modulation (PFM) for high light load efficiency
- Ease of use
  - Peak current mode control with internal loop compensation
  - Fixed 500kHz switching frequency
  - Internal 5ms soft start
  - Frequency spread spectrum to reduce EMI
  - Overcurrent protection for both MOSFETs with hiccup mode protection
  - Non-latched protection for over temperature protection (OTP), overcurrent protection (OCP), overvoltage protection (OVP), and undervoltage lockout (UVLO)
  - P2P, B2B with TPS54202
  - SOT-23 (6) package

2 Applications

- 12V, 24V distributed power-bus supply
- Industry application
  - White goods
- Consumer application
  - Audio
  - Set-Top Box (STB), Digital Television (DTV)
  - Printer

3 Description

The TPS54202x is a 4.5V to 30V input voltage range, 2A synchronous buck converter. The device includes two integrated switching FETs, internal loop compensation and 5ms internal soft start to reduce component count.

By integrating the MOSFETs and employing the SOT-23 package, the TPS54202x achieves the high power density and offers a small footprint on the PCB. TPS542025 has fixed 5V output which saves BOM by further reducing FB resistors. TPS542021 has adjustable output by a different FB resistor configuration.

The TPS54202x operates in pulse frequency modulation for high light load efficiency and reduces the power loss. The frequency spread spectrum operation is introduced for Electromagnetic Interference (EMI) reduction.
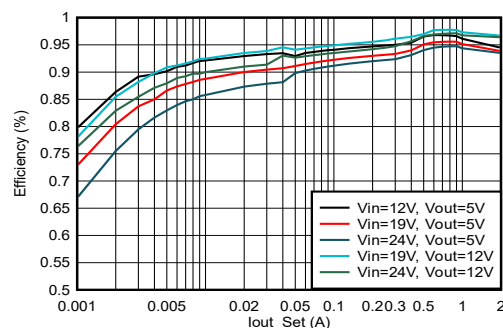
Cycle-by-cycle current limit in both high-side MOSFET protects the converter in an overload condition and is enhanced by a low-side MOSFET freewheeling current limit which prevents current runaway. Hiccup mode protection is triggered if the overcurrent condition has persisted for longer than the present time.

Device Information

PART NUMBER	PACKAGE[1]	PACKAGE SIZE[2]
TPS542021	DDC (SOT-23-THN, 6)	2.9mm × 2.8mm
TPS542025		

(1) For more information, see Section 10.
(2) The package size (length × width) is a nominal value and includes pins, where applicable.

TPS54202x Simplified Schematic

Efficiency vs Output Current

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4 Pin Configuration and Functions
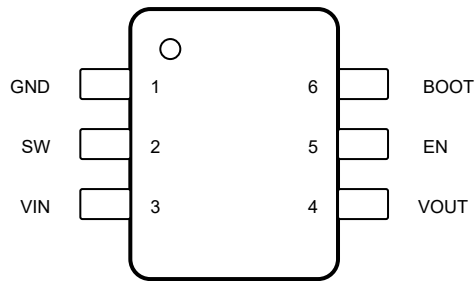
Figure 4-1. 6-Pin SOT-23 DDC Package (Top View)

Table 4-1. Pin Functions

PIN		TYPE[1]	DESCRIPTION
NAME	NO.		
BOOT	6	O	Supply input for the high-side NFET gate drive circuit. Connect a 0.1μF capacitor between BOOT and SW pins.
EN	5	I	This pin is the enable pin. Float the EN pin to enable.
FB	4	I	Converter feedback input. Connect to output voltage with feedback resistor divider for TPS542021, connect to output capacitors to get fixed 5V for TPS542025.
GND	1	—	Ground pin. Source terminal of low-side power NFET as well as the ground terminal for controller circuit. Connect sensitive VFB to this GND at a single point.
SW	2	O	Switch node connection between high-side NFET and low-side NFET.
VIN	3	—	Input voltage supply pin. The drain terminal of high-side power NFET.

(1)   O = Output; I = Input

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5 Specifications

5.1 Absolute Maximum Ratings

Over the recommended operating junction temperature range of –40°C to +150°C , unless otherwise noted[1]

		MIN	MAX	UNIT
Input voltage range, V_I	VIN	–0.3	32	V
	EN	–0.3	7	V
	FB	–0.3	7	V
Output voltage range, V_O	BOOT-SW	–0.3	7	V
	SW	–0.3	32	V
	SW (20ns transient)	–5	32	V
Operating junction temperature[2], T_J		–40	150	°C
Storage temperature range, T_{stg}		–65	150	°C

(1)   Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. A*Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

(2)   Operating at junction temperatures greater than 150°C, although possible, degrades the lifetime of the device.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001[1]	±2500	V
		Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002, all pins[2]	±1500	

(1)   JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
(2)   JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_I	Input voltage range	VIN	4.5	30	V
		EN	–0.1	5.5	V
		FB	–0.1	5.5	V
V_O	Output voltage range	BOOT-SW	–0.1	5.5	V
		SW	–0.1	30	V
T_J	Operating junction temperature		–40	150	°C

5.4 Thermal Information

		TPS54202x		UNIT
THERMAL METRIC [1]		DDC (SOT-23-THN, 6)		
		JEDEC[2]	EVM[3]	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	118.6	N/A	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	63.6	N/A	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	34.4	N/A	°C/W
ψ_{JT}	Junction-to-top characterization parameter	18.5	N/A	°C/W
ψ_{JB}	Junction-to-board characterization parameter	33.7	N/A	°C/W
$R_{\theta JA\_EVM}$	Junction-to-ambient thermal resistance on official EVM board	N/A	57.2	°C/W

(1)   For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application note.

(2)   The value of $R_{\theta JA}$ given in this table is only valid for comparison with other packages and can not be used for design purposes. These values were simulated on a standard JEDEC board. They do not represent the performance obtained in an actual application.

Product Folder Links: *TPS542021 TPS542025*

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(3)   The real R$_{\theta JA}$ is tested on TI EVM.

5.5 Electrical Characteristics

The electrical ratings specified in this section apply to all specifications in this document, unless otherwise noted. These specifications are interpreted as conditions that do not degrade the device parametric or functional specifications for the life of the product containing it. T$_J$ = –40°C to +150°C, V$_{IN}$ = 4.5V to 30V, (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT SUPPLY						
V$_{IN}$	Input voltage range		4.5		30	V
I$_Q$	Non switching quiescent current	EN =5V, VFB = 1V		26		µA
I$_{OFF}$	Shut down current	EN = GND		2		µA
V$_{IN(UVLO)}$	VIN undervoltage lockout	Rising V$_{IN}$	3.9	4.2	4.5	V
		Falling V$_{IN}$	3.4	3.7	4	V
	Hysteresis		400	480	650	mV
ENABLE (EN PIN)						
V$_{(EN\_RISING)}$	Enable threshold	Rising		1.21	1.28	V
V$_{(EN\_FALLING)}$		Falling	1.1	1.19		V
I$_{(EN\_INPUT)}$	Input current	V$_{EN}$ = 1V		0.7		µA
I$_{(EN\_HYS)}$	Hysteresis current	V$_{EN}$ = 1.5V		1.55		µA
FEEDBACK AND ERROR AMPLIFIER						
V$_{FB}$	Feedback voltage	V$_{IN}$ = 12V	0.587	0.596	0.605	V
PULSE SKIP MODE						
I$_{(SKIP)}$ [1]	Pulse skip mode peak inductor current threshold	V$_{IN}$ = 24 V, V$_{OUT}$ = 5V, L = 15µH		750		mA
POWER STAGE						
R$_{(HSD)}$	High-side FET on resistance	T$_A$ = 25°C, V$_{BST}$ – SW = 6V		100		mΩ
R$_{(LSD)}$	Low-side FET on resistance	T$_A$ = 25°C, V$_{IN}$ = 12V		60		mΩ
CURRENT LIMIT						
I$_{(LIM\_HS)}$	High side current limit		2.5	3.2	3.9	A
I$_{(LIM\_LS)}$	Low side source current limit		2	3	4.3	A
OSCILLATOR						
F$_{sw}$	Centre switching frequency		390	500	630	kHz
OVER TEMPERATURE PROTECTION						
Thermal Shutdown [1]	Rising temperature			160		°C
	Hysteresis			10		°C
	Hiccup time			32768		Cycles

(1)   Not production tested

5.6 Timing Requirements

		MIN	TYP	MAX	UNIT
OVERCURRENT PROTECTION					
t$_{HIC\_WAIT}$	Hiccup up wait time		512		Cycles
t$_{HIC\_RESTART}$	Hiccup up time before restart		16384		Cycles
t$_{SS}$	Soft-start time		5		mS
ON TIME CONTROL					
t$_{MIN\_ON}$ [1]	Minimum on time, measured at 90% to 90% and 1A loading		110		ns

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5.7 Typical Characteristics

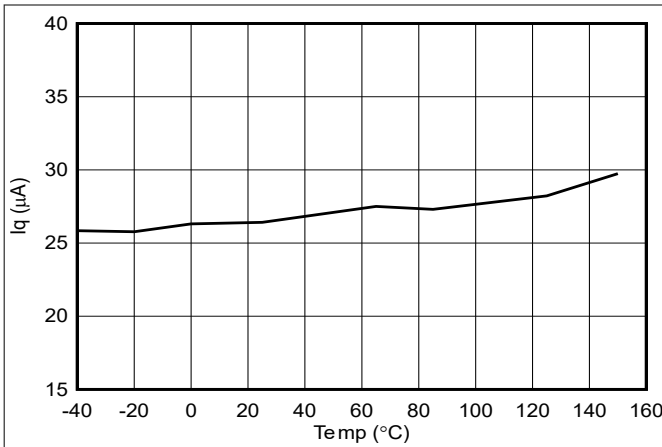V_{IN} = 12V, unless otherwise specified

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Figure 5-1. Non-Switching Operating Quiescent Current vs Junction Temperature
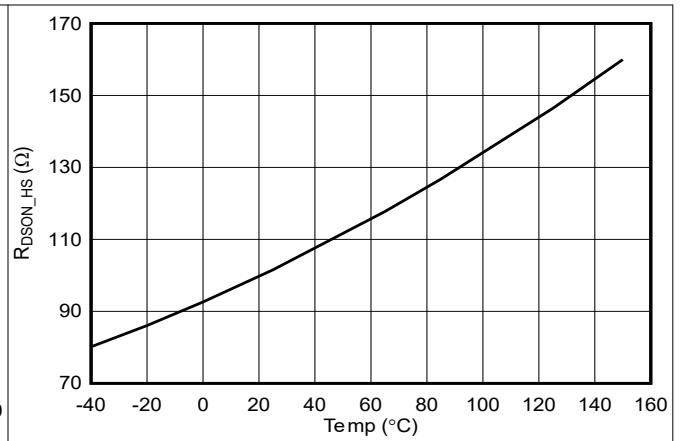

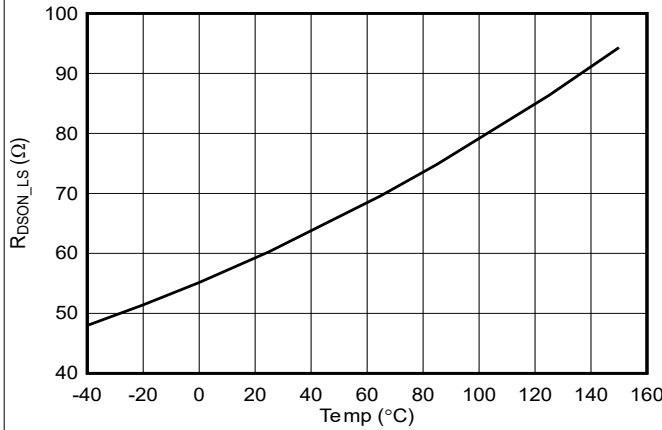**Figure 5-2. High-Side Resistance vs Junction Temperature**

Figure 5-3. Low-Side FET On Resistance vs Junction Temperature
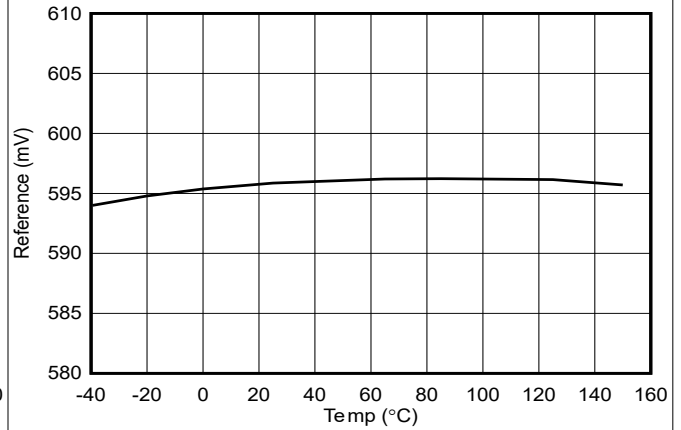

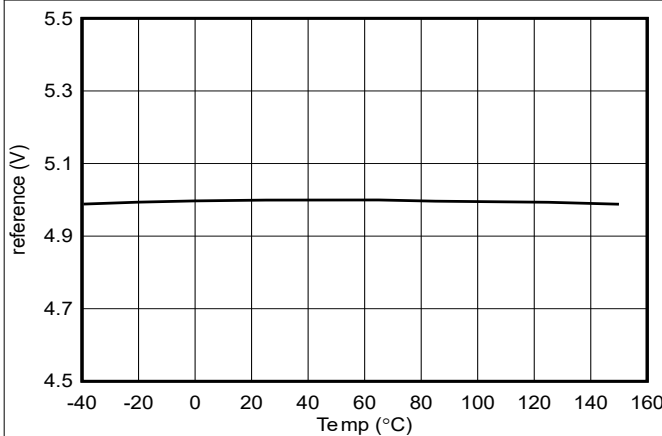**Figure 5-4. TPS542021 Reference Voltage vs Junction Temperature**

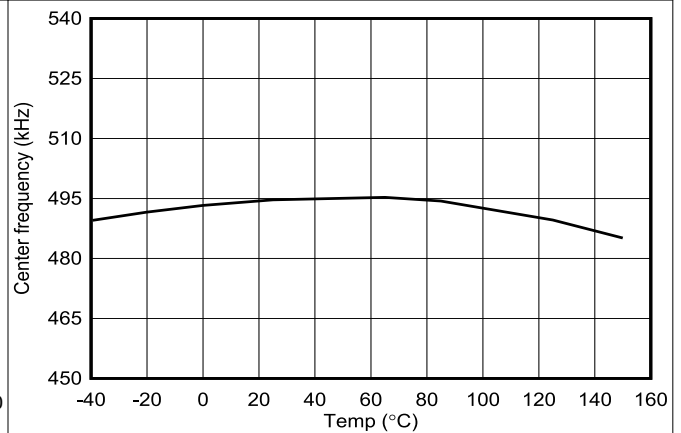**Figure 5-5. TPS542025 Reference Voltage vs Junction Temperature**

Figure 5-6. Centre Switching Frequency vs Junction Temperature

Product Folder Links: *TPS542021 TPS542025*

5.7 Typical Characteristics (continued)

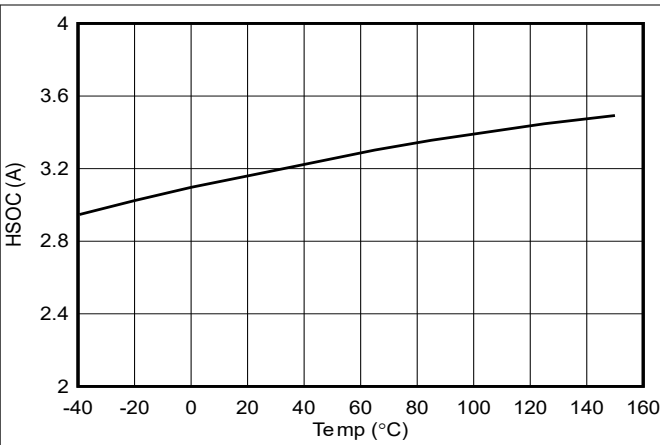V_{IN} = 12V, unless otherwise specified

Figure 5-7. High-Side Current Limit Threshold vs Junction Temperature
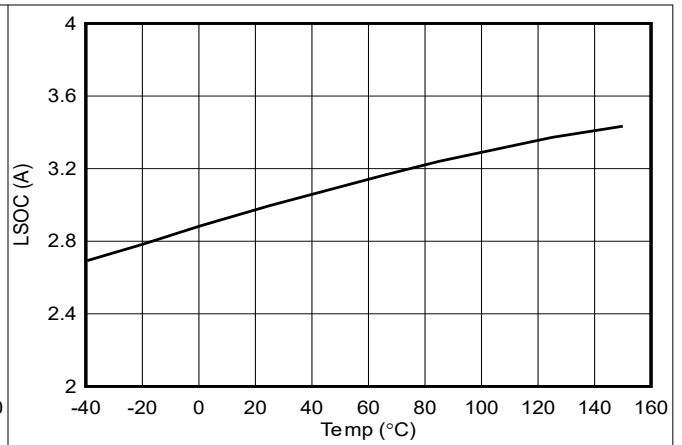

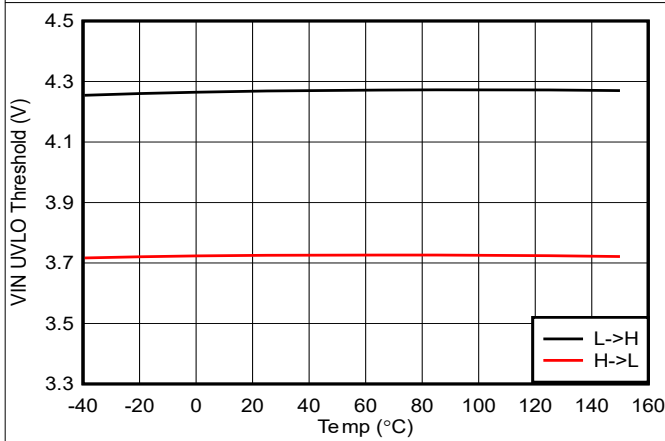Figure 5-8. Low-Side Current Limit Threshold vs Junction Temperature

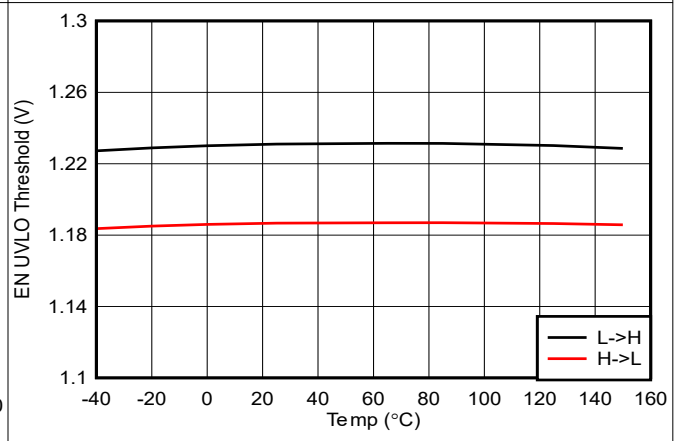Figure 5-9. VIN UVLO Threshold vs Junction Temperature
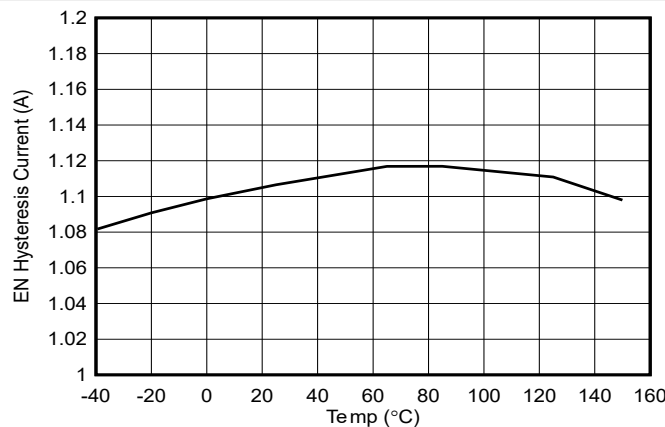

Figure 5-10. EN Threshold vs Junction Temperature

Figure 5-11. EN Hysteresis Current vs Junction Temperature

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Product Folder Links: *TPS542021 TPS542025*

6 Detailed Description

6.1 Overview

The TPS54202x device is a 30V, 2A, synchronous step-down (buck) converter with two integrated n-channel MOSFETs. To improve performance during line and load transients the device implements a constant-frequency, peak current mode control which reduces output capacitance. The optimized internal compensation network minimizes the external component counts and simplifies the control loop design.

The switching frequency is fixed to 500kHz. The TPS542025 has fixed 5V output while TPS542021 has adjustable output.

The device begins switching at VIN equal to 4.5V. The operating current is 26µA typically when not switching and under no load. When the device is disabled, the supply current is 2µA typically.

The integrated 100mΩ high-side MOSFET and 60mΩ allow for high efficiency power supply designs with continuous output currents up to 2A.

The device reduces the external component count by integrating the boot recharge diode. The bias voltage for the integrated high-side MOSFET is supplied by an external capacitor on the BOOT to PH pins. The boot capacitor voltage is monitored by an UVLO circuit and turns the high-side MOSFET off when the voltage falls below a preset threshold of 2.1V typically.

The device minimizes excessive output overvoltage transients by taking advantage of the overvoltage comparator. When the regulated output voltage is greater than 108% of the nominal voltage, the overvoltage comparator is activated, and the high-side MOSFET is turned off and masked from turning on until the output voltage is lower than 104%.

The device has internal 5ms soft-start time to minimize inrush currents.

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6.2 Functional Block Diagram
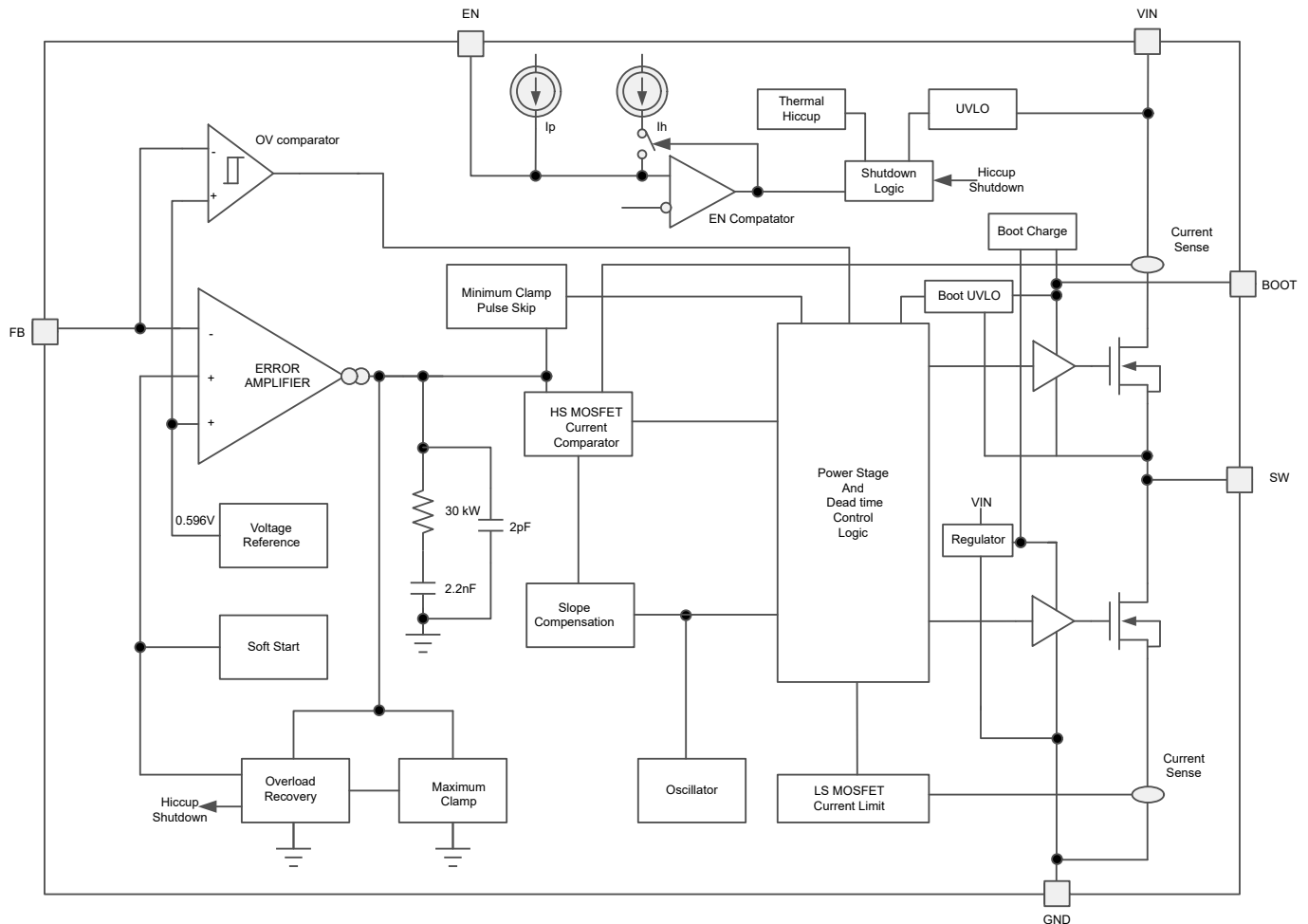
6.3 Feature Description

6.3.1 Fixed-Frequency PWM Control

The device uses a fixed-frequency, peak current-mode control. For TPS542025, the output voltage is fixed 5V by connecting the FB pin to Vout. For TPS542021, the output voltage of is compared through external resistors on the FB pin to an internal voltage reference by an error amplifier. An internal oscillator initiates the turn on of the high-side power switch. The error amplifier output is compared to the current of the high-side power switch. When the power-switch current reaches the error amplifier output voltage level, the high side power switch is turned off and the low-side power switch is turned on. The error amplifier output voltage increases and decreases as the output current increases and decreases. The device implements a current-limit by clamping the error amplifier voltage to a maximum level and also implements a minimum clamp for improved transient-response performance.

6.3.2 Pulse Frequency Mode

The TPS54202x is designed to operate in pulse frequency mode at light load currents to boost light load efficiency. When the peak inductor current is lower than 750mA typically, the device enters pulse frequency mode. When the device is in pulse frequency mode, the error amplifier output voltage is clamped which prevents the high side integrated MOSFET from switching. The peak inductor current must rise above 750mA and exit pulse frequency mode. Because the integrated current comparator catches the peak inductor current only, the average load current entering pulse frequency mode varies with the applications and external output filters.

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6.3.3 Error Amplifier

The device has a trans-conductance amplifier as the error amplifier. The error amplifier compares the FB voltage to the lower of the internal soft-start voltage or the internal 0.596V voltage reference. The transconductance of the error amplifier is 240µA/V typically. The frequency compensation components are placed internal between the output of the error amplifier and ground.

6.3.4 Slope Compensation and Output Current

The device adds a compensating ramp to the signal of the switch current. This slope compensation prevents sub-harmonic oscillations as the duty cycle increases. The available peak inductor current remains constant over the full duty-cycle range.

6.3.5 Enable and Adjusting Undervoltage Lockout

The EN pin provides electrical on and off control of the device. When the EN pin voltage exceeds the threshold voltage, the device begins operation. If the EN pin voltage is pulled below the threshold voltage, the regulator stops switching and enters the low-quiescent (IQ) state.

The EN pin has an internal pullup-current source, which allows the user to float the EN pin to enable the device. If an application requires control of the EN pin, use open-drain or open-collector output logic to interface with the pin.

The device implements internal undervoltage-lockout (UVLO) circuitry on the VIN pin. The device is disabled when the VIN pin voltage falls below the internal VIN UVLO threshold. The internal VIN UVLO threshold has a hysteresis of 480mV.

If an application requires a higher UVLO threshold on the VIN pin, then the EN pin can be configured as shown in Figure 6-1. When using the external UVLO function, TI recommends setting the hysteresis at a value greater than 500mV.

The EN pin has a small pullup current, Ip, which sets the default state of the pin to enable when no external components are connected. The pullup current is also used to control the voltage hysteresis for the UVLO function because the pullup current increases by Ih when the EN pin crosses the enable threshold. Use Equation 1 and Equation 2 to calculate the values of R4 and R5 for a specified UVLO threshold.
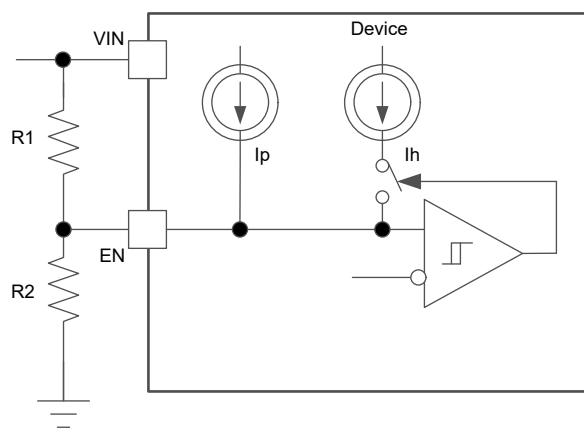

Figure 6-1. Adjustable VIN Undervoltage Lockout

$$R_4 = \frac{\frac{V_{ENfalling}}{V_{ENrising}} \times V_{START} - V_{STOP}}{I_p \times \left(1 - \frac{V_{ENfalling}}{V_{ENrising}}\right) + I_h} \tag{1}$$

$$R_5 = \frac{R_4 \times V_{ENfalling}}{V_{STOP} - V_{ENfalling} + (I_h + I_p) \times R_4} \tag{2}$$

Product Folder Links: *TPS542021 TPS542025*

Where:

I_p = 0.7µA
I_h = 1.55µA
$V_{ENfalling}$ = 1.19V
$V_{ENrising}$ = 1.22V

6.3.6 Safe Start-Up into Prebiased Outputs

The device has been designed to prevent the low-side MOSFET from discharging a prebiased output. During monotonic prebiased start-up, both high-side and low-side MOSFETs are not allowed to be turned on until the internal soft-start voltage is higher than the FB pin voltage.

6.3.7 Voltage Reference

The voltage reference system produces a precise ±2% voltage-reference overtemperature by scaling the output of a temperature stable bandgap circuit. The typical voltage reference is designed at 0.596V.

6.3.8 Adjusting Output Voltage

The output voltage is set with a resistor divider from the output node to the FB pin. TI recommends to use divider resistors with 1% tolerance or better. Start with a 100kΩ for the upper resistor divider, and use Equation 3 to calculate the output voltage. To improve efficiency at light loads consider using larger value resistors. If the values are too high the regulator is more susceptible to noise and voltage errors from the FB input current are noticeable.

$$V_{OUT} = V_{ref} \times \left(\frac{R_2}{R_3} + 1 \right)$$

(3)

6.3.9 Internal Soft Start

The TPS54202x uses the internal soft-start function. The internal soft start time is set to 5ms typically.

6.3.10 Bootstrap Voltage (BOOT)

The TPS54202x has an integrated boot regulator and requires a 0.1µF ceramic capacitor between the BOOT and SW pins to provide the gate drive voltage for the high-side MOSFET. A ceramic capacitor with an X7R or X5R grade dielectric is recommended because of the stable characteristics over temperature and voltage. To improve drop out, the device is designed to operate at 100% duty cycle as long as the BOOT to SW pin voltage is greater than 2.1V typically.

6.3.11 Overcurrent Protection

The device is protected from overcurrent conditions by cycle-by-cycle current limiting on both the high-side MOSFET and the low-side MOSFET.

6.3.11.1 High-Side MOSFET Overcurrent Protection

The device implements current mode control which uses the internal COMP voltage to control the turn off of the high-side MOSFET and the turn on of the low-side MOSFET on a cycle-by-cycle basis. During each cycle, the switch current and the current reference generated by the internal COMP voltage are compared. When the peak switch current intersects the current reference, the high-side switch turns off.

6.3.11.2 Low-Side MOSFET Overcurrent Protection

While the low-side MOSFET is turned on, the conduction current is monitored by the internal circuitry. During normal operation, the low-side MOSFET sources current to the load. At the end of every clock cycle, the low-side MOSFET sourcing current is compared to the internally set low-side sourcing current-limit. The inductor valley current is exceeded the low-side source current limit, the high-side MOSFET does not turn on and the low-side MOSFET stays on for the next cycle. The high-side MOSFET turns on again when the inductor valley current is below the low-side sourcing current-limit at the start of a cycle.

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Furthermore, if an output overload condition occurs for more than the hiccup wait time, which is programmed for 512 switching cycles, the device shuts down and restarts after the hiccup time of 16384 cycles. The hiccup mode helps to reduce the device power dissipation under severe overcurrent conditions.

6.3.12 Spread Spectrum

To reduce EMI, TPS54202x introduces frequency spread spectrum. The jittering span is ±6% of the switching frequency with 1/512 swing frequency.
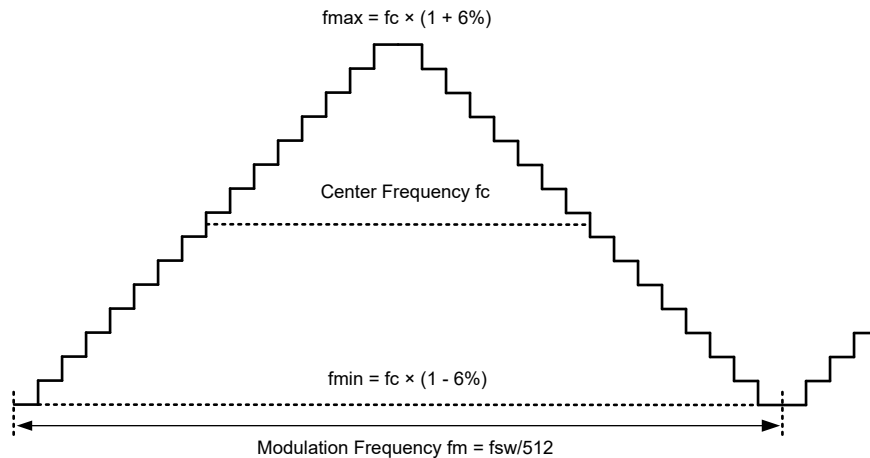

Figure 6-2. Frequency Spread Spectrum Diagram

6.3.13 Output Overvoltage Protection (OVP)

The TPS54202x incorporates an overvoltage transient protection (OVTP) circuit to minimize output voltage overshoot when recovering from output fault conditions or strong unload transients. The OVP circuit includes an overvoltage comparator to compare the FB pin voltage and internal thresholds. When the FB pin voltage goes above 108% × Vref, the high-side MOSFET is forced off. When the FB pin voltage falls below 104% × Vref, the high-side MOSFET is enabled again.

6.3.14 Thermal Shutdown

The internal thermal-shutdown circuitry forces the device to stop switching if the junction temperature exceeds 160°C typically. When the junction temperature drops below 150°C typically, the internal thermal-hiccup timer begins to count. The device reinitiates the power-up sequence after the built-in thermal-shutdown hiccup time (32768 cycles) is over.

6.4 Device Functional Modes

6.4.1 Normal Operation

When the input voltage is above the UVLO threshold, the TPS54202x can operate in the normal switching modes. Normal continuous conduction mode (CCM) occurs when inductor peak current is above 0A. In CCM, the device operates at a fixed frequency.

6.4.2 Eco-mode Operation

The devices are designed to operate in high-efficiency pulse-skipping mode under light load conditions. Pulse skipping initiates when the switch current falls to 0A. During pulse skipping, the low-side FET turns off when the switch current falls to 0A. The switching node (the SW pin) waveform takes on the characteristics of discontinuous conduction mode (DCM) operation and the apparent switching frequency decreases. As the output current decreases, the perceived time between switching pulses increases.

Product Folder Links: *TPS542021 TPS542025*

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

The TPS542021 device is typically used as a step-down converter, which converts an input voltage from 5V to 30V to fixed output voltage 5V.

7.2 Typical Application
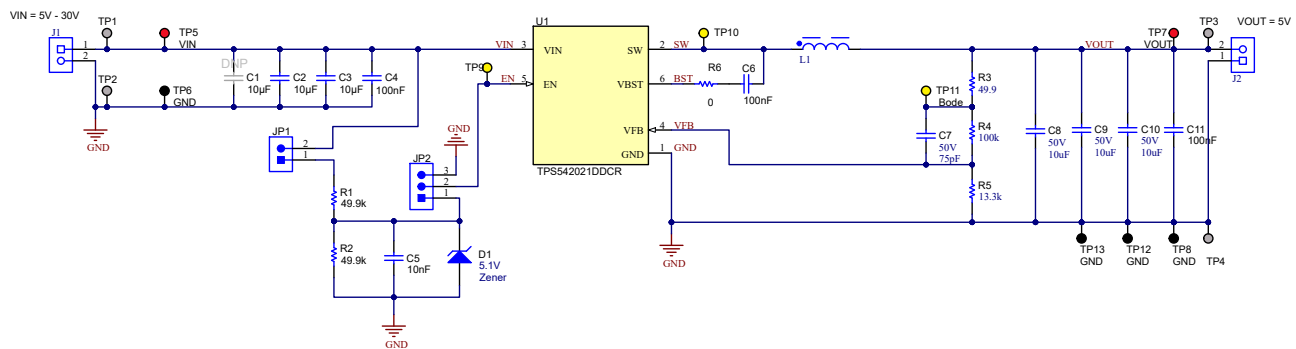
7.2.1 TPS542021 5V to 30V Input, 5V Output Converter

Figure 7-1. 5V, 2A Reference Design

7.2.2 Design Requirements

For this design example, use the parameters in the following table.

Table 7-1. Design Parameters

PARAMETER	VALUE
Input voltage range	5V to 30V
Output voltage	5V
Output current	2A
Transient response, 2A load step	ΔV_{OUT} = ±5 %
Output voltage ripple	10mVpp
Switching frequency	500kHz

Product Folder Links: *TPS542021 TPS542025*

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7.2.3 Detailed Design Procedure

7.2.3.1 Input Capacitor Selection

The device requires an input decoupling capacitor, and a bulk capacitor is needed depending on the application. TI recommends a ceramic capacitor over 10µF for the decoupling capacitor. An additional 0.1µF capacitor (C4) from VIN to GND is optional to provide additional high frequency filtering. The capacitor voltage rating must be greater than the maximum input voltage.

Use the following equation to calculate the input ripple voltage (ΔV_{IN}).

$$\Delta V_{IN} = \frac{I_{OUT(MAX)} \times 0.25}{C_{BULK} \times f_{SW}} + I_{OUT(MAX)} \times ESR_{MAX} \tag{4}$$

where:

- C_{BULK} is the bulk capacitor value
- f_{SW} is the switching frequency
- $I_{OUT(MAX)}$ is the maximum loading current
- ESR_{MAX} is maximum series resistance of the bulk capacitor

The maximum RMS (root mean square) ripple current must also be checked. For worst case conditions, use Equation 5 to calculate $I_{CIN(RMS)}$.

$$I_{CIN(RMS)} = \frac{I_{OUT(MAX)}}{2} \tag{5}$$

The actual input-voltage ripple is greatly affected by parasitic associated with the layout and the output impedance of the voltage source. *Design Requirements* shows the actual input voltage ripple for this circuit, which is larger than the calculated value. The maximum voltage across the input capacitors is VIN (MAX) + ΔVIN/2. The selected bypass capacitor is rated for 50V and the ripple current capacity is greater than 2A. Both values provide ample margin. The maximum ratings for voltage and current must not be exceeded under any circumstance.

7.2.3.2 Bootstrap Capacitor Selection

A 0.1µF ceramic capacitor must be connected between the BOOT to SW pin for proper operation. TI recommends to use a ceramic capacitor.

7.2.3.3 Output Voltage Setpoint

The output voltage of the TPS542021 device is externally adjustable using a resistor divider network. The divider network is comprised of R4 and R5. Use the following equations to calculate the relationship of the output voltage to the resistor divider.

$$R_5 = \frac{R_4 \times V_{ref}}{V_{OUT} - V_{ref}} \tag{6}$$

$$V_{OUT} = V_{ref} \times \left(\frac{R_4}{R_5} + 1\right) \tag{7}$$

Select a value of R4 to be approximately 100kΩ. Slightly increasing or decreasing R5 can result in closer output voltage matching when using standard value resistors. In this design, R4 = 100kΩ and R5 = 13.3kΩ, which results in a 5V output voltage. The 49.9Ω resistor, R3, is provided as a convenient location to break the control loop for stability testing.

7.2.3.4 Undervoltage Lockout Setpoint

The undervoltage lockout (UVLO) setpoint can be adjusted using the external-voltage divider network of R1 and R2. R1 is connected between the VIN and EN pins of the TPS542021 device. R2 is connected between the EN and GND pins. The UVLO has two thresholds, one for power up when he input voltage is rising and one

Product Folder Links: *TPS542021 TPS542025*

for power down or brown outs when the input voltage is falling. Use Equation 1 and Equation 2 to calculate the values for the upper and lower resistor values of R1 and R2.

7.2.3.5 Output Filter Components

Two components must be selected for the output filter, the output inductor (L_O) and C_O.

7.2.3.5.1 Inductor Selection

Use the following equation to calculate the minimum value of the output inductor (L_{MIN}).

$$L_{MIN} = \frac{V_{OUT} \times (V_{IN(MAX)} - V_{OUT})}{V_{IN(MAX)} \times K_{IND} \times I_{OUT} \times f_{SW}} \tag{8}$$

Where:

K_{IND} is a coefficient that represents the amount of inductor ripple current relative to the maximum output current.

In general, the value of K_{IND} is at the discretion of the designer; however, the following guidelines can be used. For designs using low-ESR output capacitors, such as ceramics, a value as high as $K_{IND} = 0.3$ can be used.

For this design example, use $K_{IND} = 0.3$. The minimum inductor value is calculated as 13.7µH. For this design, a close standard value of 15µH was selected for L_{MIN}.

For the output filter inductor, the RMS current and saturation current ratings must not be exceeded. Use the following equation to calculate the RMS inductor current ($I_{L(RMS)}$).

$$I_{L(MAX)} = \sqrt{I_{OUT(MAX)}^2 + \frac{1}{12} \times \left(\frac{V_{OUT} \times (V_{IN(MAX)} - V_{OUT})}{V_{IN(MAX)} \times L_O \times f_{SW} \times 0.8}\right)^2} \tag{9}$$

Use the following equation to calculate the peak inductor current ($I_{L(PK)}$).

$$I_{L(PK)} = I_{OUT(MAX)} + \frac{V_{OUT} \times (V_{IN(MAX)} - V_{OUT})}{V_{IN(MAX)} \times L_O \times f_{SW} \times 1.6} \tag{10}$$

Smaller or larger inductor values can be used depending on the amount of ripple current the designer wants to allow so long as the other design requirements are met. Larger value inductors have lower AC current and result in lower output voltage ripple. Smaller inductor values increase AC current and output voltage ripple.

7.2.3.5.2 Output Capacitor Selection

Consider three primary factors when selecting the value of the output capacitor. The output capacitor determines the modulator pole, the output voltage ripple, and how the regulator responds to a large change in load current. The output capacitance must be selected based on the more stringent of these three criteria.

The desired response to a large change in the load current is the first criterion. The output capacitor must supply the load with current when the regulator cannot. This situation occurs if the desired hold-up times are present for the regulator. In this case, the output capacitor must hold the output voltage above a certain level for a specified amount of time after the input power is removed. The regulator is also temporarily unable to supply sufficient output current if a large, fast increase occurs affecting the current requirements of the load, such as a transition from no load to full load. The regulator usually requires two or more clock cycles for the control loop to notice the change in load current and output voltage and to adjust the duty cycle to react to the change. The output capacitor must be sized to supply the extra current to the load until the control loop responds to the load change. The output capacitance must be large enough to supply the difference in current for 2 clock cycles while only allowing a tolerable amount of drop in the output voltage. Use the following equation to calculate the minimum required output capacitance.

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$$C_O = \frac{2 \times \Delta I_{OUT}}{f_{SW} \times \Delta V_{OUT}} \qquad (11)$$

where:

- ΔI_{OUT} is the change in output current
- f_{SW} is the switching frequency of the regulator
- $\Delta V_{(OUT)}$b is the allowable change in the output voltage

For this example, the transient load response is specified as a 5% change in the output voltage, V_{OUT}, for a load step of 1.5A. For this example, ΔI_{OUT} = 1.5A and ΔV_{OUT} = 0.05 × 5 = 0.25V. Using these values results in a minimum capacitance of 24µF. This value does not consider the ESR of the output capacitor in the output voltage change. For ceramic capacitors, the ESR is usually small enough to ignore in this calculation.

Equation 12 calculates the minimum output capacitance required to meet the output voltage ripple specification. In this case, the maximum output voltage ripple is 30mV. Under this requirement, Equation 12 yields 4.56µF.

$$C_O = \frac{1}{8 \times f_{SW}} \times \frac{1}{\frac{V_{OUTripple}}{I_{ripple}}} \qquad (12)$$

where:

- f_{SW} is the switching frequency
- $V_{(OUTripple)}$ is the maximum allowable output voltage ripple
- $I_{(ripple)}$ is the inductor ripple current

Use Equation 13 to calculate the maximum ESR an output capacitor can have to meet the output-voltage ripple specification. Equation 13 indicates the ESR must be less than 54.8mΩ. In this case, the ESR of the ceramic capacitor is much smaller than 54.8mΩ.

$$R_{ESR} < \frac{V_{OUTripple}}{I_{ripple}} \qquad (13)$$

The output capacitor can affect the crossover frequency f_o. Considering to the loop stability and effect of the internal parasitic parameters, choose the crossover frequency less than 40kHz without considering the feed forward capacitor. A simple estimation for the crossover frequency without feed forward capacitor C6 is shown in Equation 14, assuming C_{OUT} has small ESR.

$$f_O = \frac{3.95}{V_{OUT} \times C_{OUT}} \qquad (14)$$

Additional capacitance deratings for aging, temperature, and DC bias must be considered, which increases this minimum value. For this example, two 22uF 25V, X7R ceramic capacitors are used. Capacitors generally have limits to the amount of ripple current the capacitors can handle without failing or producing excess heat. An output capacitor that can support the inductor ripple current must be specified. Some capacitor data sheets specify the RMS value of the maximum ripple current. Use Equation 15 to calculate the RMS ripple current that the output capacitor must support. For this application, Equation 15 yields 79mA for each capacitor.

$$I_{COUT(RMS)} = \frac{1}{\sqrt{12}} \times \left(\frac{V_{OUT} \times (V_{IN(MAX)} - V_{OUT})}{V_{IN(MAX)} \times L_O \times f_{SW} \times N_C} \right) \qquad (15)$$

7.2.3.5.3 Feed-Forward Capacitor

In some cases, a feedforward capacitor can be used across R_{FBT} to improve the load transient response or improve the loop phase margin. This statement is especially true when values of R_{FBT} > 100kΩ are used. Large values of R_{FBT} in combination with the parasitic capacitance at the FB pin can create a small signal pole that interferes with the loop stability. A C_{FF} helps mitigate this effect. Use lower values to determine if any advantage is gained by the use of a C_{FF} capacitor.

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SLVSI78 – JANUARY 2025

The *Optimizing Transient Response of Internally Compensated DC-DC Converters with Feedforward Capacitor application report* is helpful when experimenting with a feedforward capacitor.

Table 7-2. Recommended Component Values

V$_{OUT}$ (V)	L (µH)	C$_{OUT}$(µF)	R2 (kΩ)	R3 (kΩ)	C6 (pF)
1.8	5.6	66	100	49.9	47
2.5	8.2	44	100	31.6	33
3.3	10	44	100	22.1	56
5	15	44	100	13.3	75
12	22	44	100	5.23	100

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7.2.4 Application Curves

The following data is tested with V_{IN} = 24V, V_{OUT} = 5V, T_A = 25°C, unless otherwise specified.
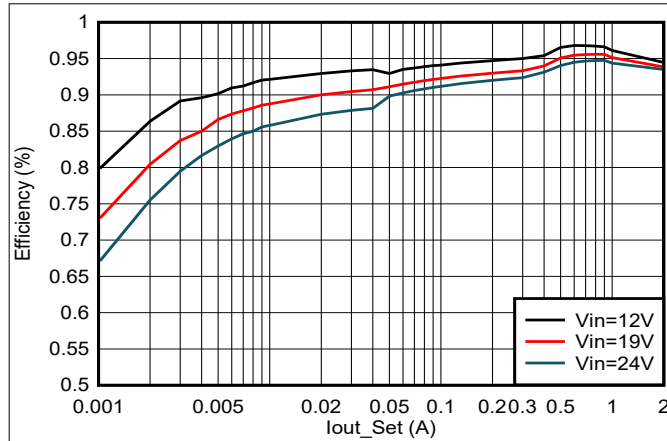
Figure 7-2. TPS542021EVM Efficiency
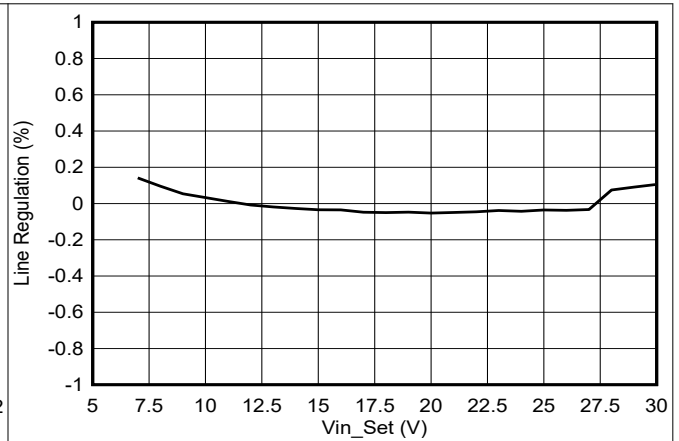
Figure 7-3. TPS542021EVM Line Regulation, I_OUT = 2A
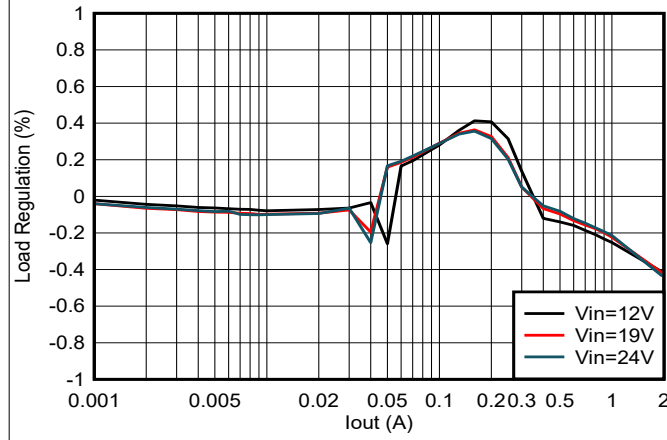
Figure 7-4. TPS542021EVM Load Regulation
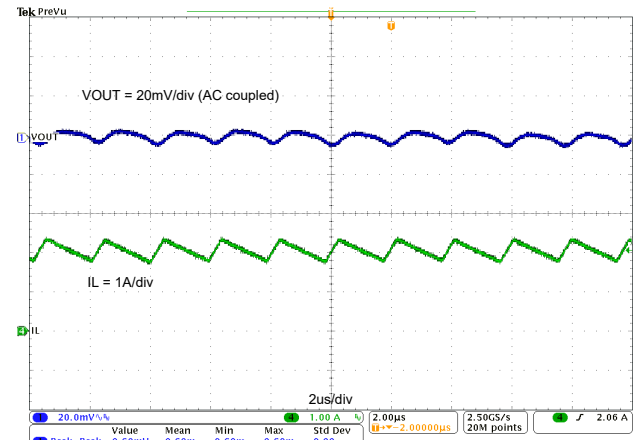

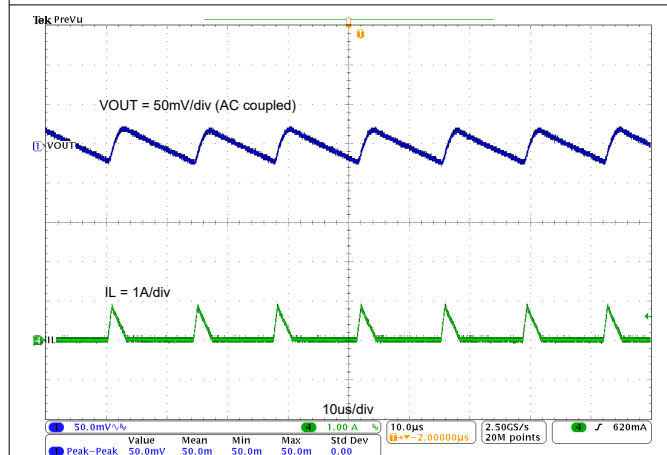**Figure 7-5. TPS542021EVM Output Voltage Ripple, I_OUT = 2A**
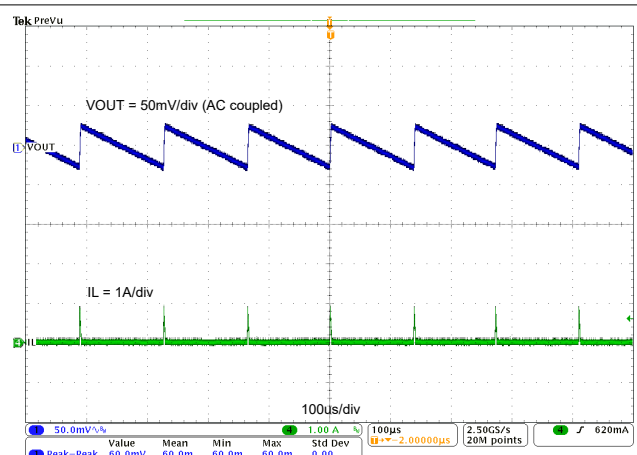

Figure 7-6. TPS542021EVM Output Voltage Ripple, I_OUT = 0.1A

Figure 7-7. TPS542021EVM Output Voltage Ripple, I_OUT = 0.01A

Product Folder Links: *TPS542021 TPS542025*

7.2.4 Application Curves (continued)

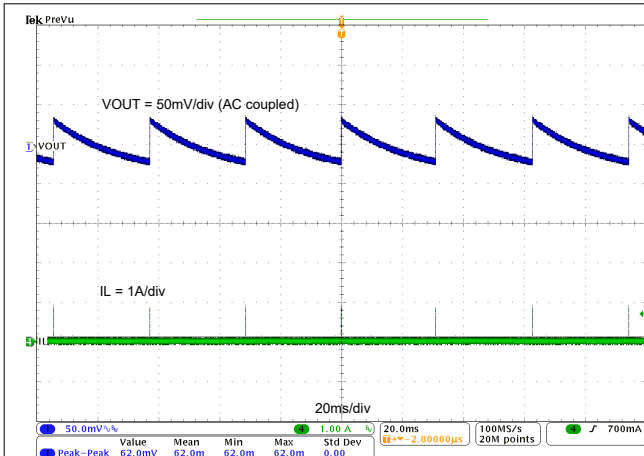The following data is tested with V_{IN} = 24V, V_{OUT} = 5V, T_A = 25°C, unless otherwise specified.

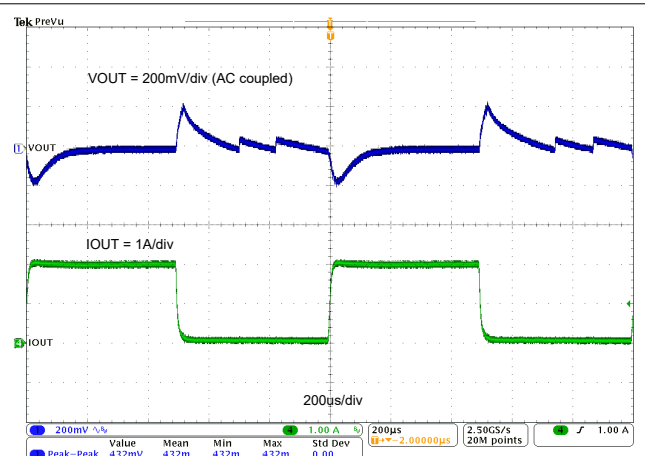**Figure 7-8. TPS542021EVM Output Voltage Ripple, I_{OUT} = 0A**

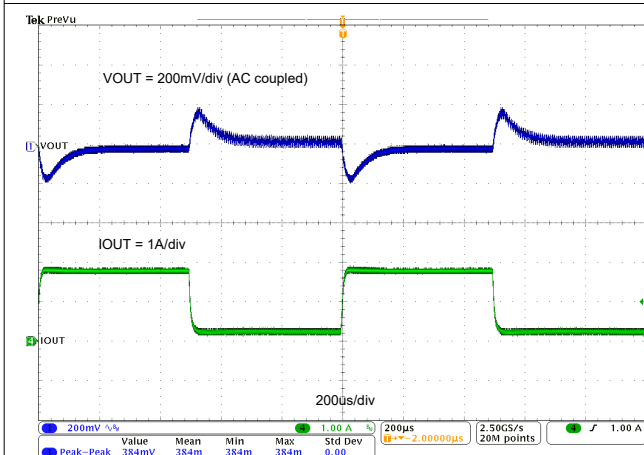**Figure 7-9. TPS542021EVM Load Transient Response, 0A to 2A Load Step**

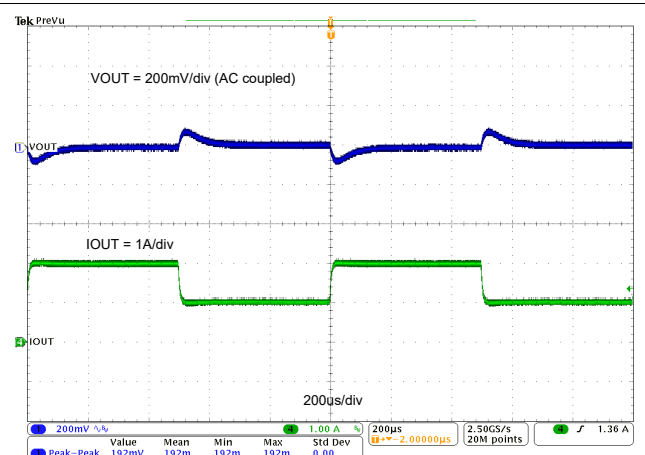**Figure 7-10. TPS542021EVM Load Transient Response, 0.2A to 1.8A Load Step**

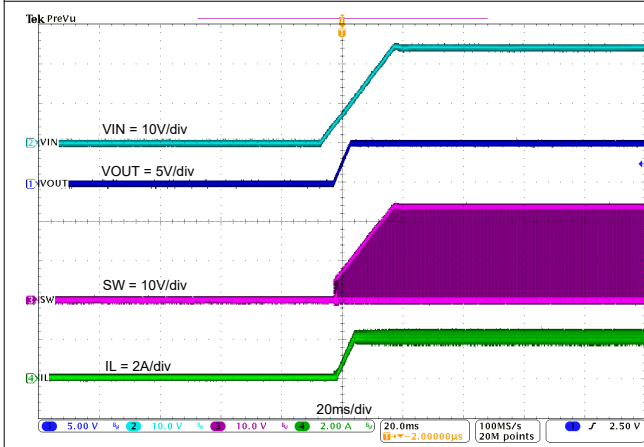**Figure 7-11. TPS542021EVM Load Transient Response, 1A to 2A Load Step**

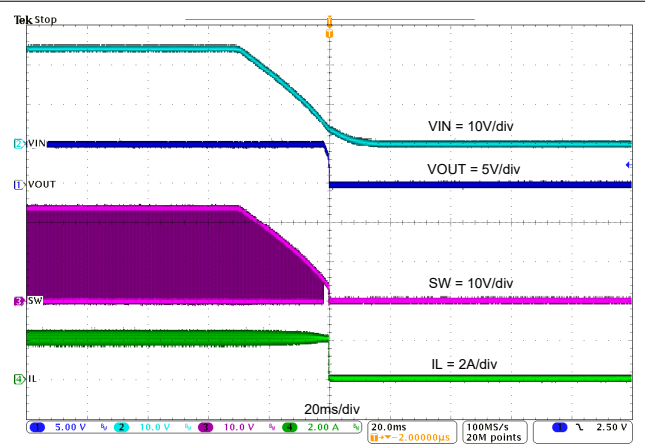**Figure 7-12. TPS542021EVM Start-Up Relative to V_{IN}**

Figure 7-13. TPS542021EVM Shutdown Relative to V_{IN}

Product Folder Links: TPS542021 TPS542025

ADVANCE INFORMATION

7.3 Power Supply Recommendations

The devices are designed to operate from an input voltage supply range between 4.5V and 30V. This input supply must be well regulated. If the input supply is located more than a few inches from the device or converter, additional bulk capacitance can be required in addition to the ceramic bypass capacitors. An electrolytic capacitor with a value of 47µF is a typical choice.

7.4 Layout

7.4.1 Layout Guidelines

- Make VIN and GND traces as wide as possible to reduce trace impedance. The wide areas are also of advantage from the view point of heat dissipation.
- Place the input capacitor and output capacitor as close to the device as possible to minimize trace impedance.
- Provide sufficient vias for the input capacitor and output capacitor.
- Keep the SW trace as physically short and wide as practical to minimize radiated emissions.
- Do not allow switching current to flow under the device.
- Connect a separate VOUT path to the upper feedback resistor.
- Make a Kelvin connection to the GND pin for the feedback path.
- Place the voltage feedback loop away from the high-voltage switching trace, and preferably have ground shield.
- Make the trace of the VFB node as small as possible to avoid noise coupling.
- Make the GND trace between the output capacitor and the GND pin as wide as possible to minimize the trace impedance.
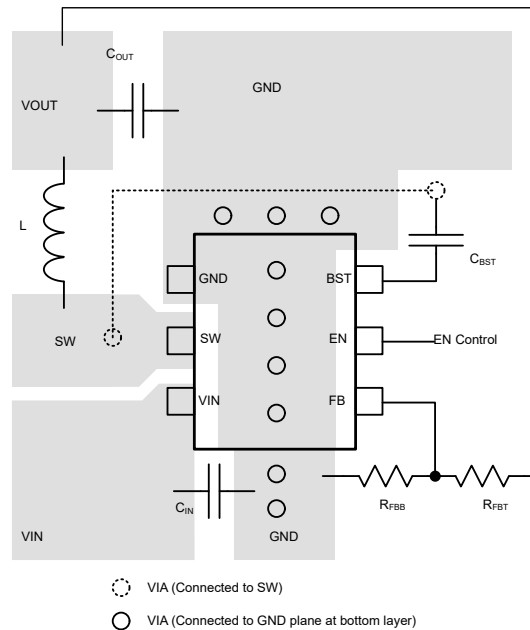
7.4.2 Layout Example

Figure 7-14. Board Layout

8 Device and Documentation Support

8.1 Device Support

8.1.1 Third-Party Products Disclaimer

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8.2 Documentation Support

8.2.1 Related Documentation

For related documentation, see the following:

Texas Instruments, *Optimizing Transient Response of Internally Compensated DC-DC Converters with Feedforward Capacitor* application report

8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.4 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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8.5 Trademarks

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8.6 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.7 Glossary

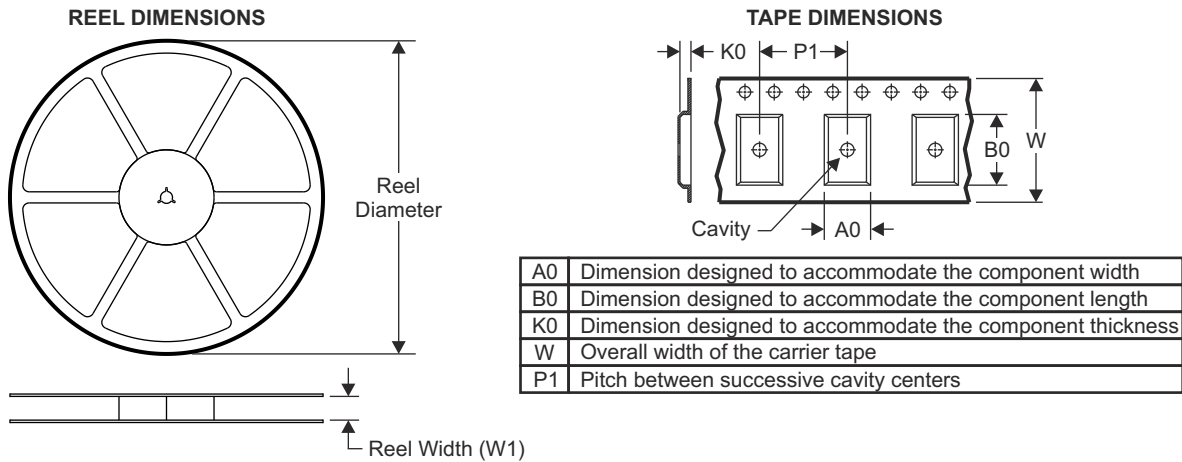TI Glossary   This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

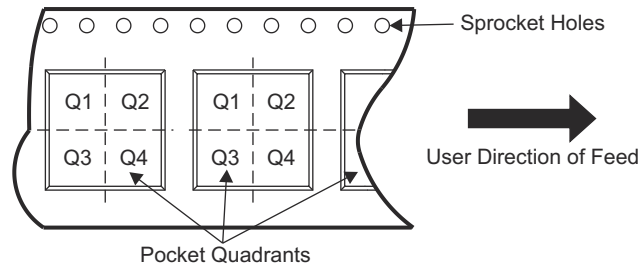| DATE	REVISION	NOTES
January 2025	*	Initial Release

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

ADVANCE INFORMATION

10.1 Tape and Reel Information

ADVANCE INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
PTPS542021DDCR	SOT-23-THIN	DDC	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
PTPS542025DDCR	SOT-23-THIN	DDC	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

Product Folder Links: *TPS542021 TPS542025*

TAPE AND REEL BOX DIMENSIONS

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
PTPS542021DDCR	SOT-23-THIN	DOC	6	3000	210.0	185.0	35.0
PTPS542025DDCR	SOT-23-THIN	DOC	6	3000	210.0	185.0	35.0

ADVANCE INFORMATION

Product Folder Links: *TPS542021 TPS542025*

PACKAGE OUTLINE

DDC0006A

SOT-23 - 1.1 max height

SMALL OUTLINE TRANSISTOR

ADVANCE INFORMATION

3.05
2.55

1.75
1.45

B

A

PIN 1
INDEX AREA

1

6

4X 0.95

1.9

3.05
2.75

3

4

6X 0.5
0.3

⊕ 0.20Ⓜ C A B

1.1
0.7

⌂ 0.1 C

4X 0°-15°

0.1
0.0 TYP

4X 4°-15°

0°-8° TYP

C

0.20 TYP
0.12

SEATING PLANE

0.25
GAGE PLANE

0.6 TYP
0.3

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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-193.

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Product Folder Links: *TPS542021 TPS542025*
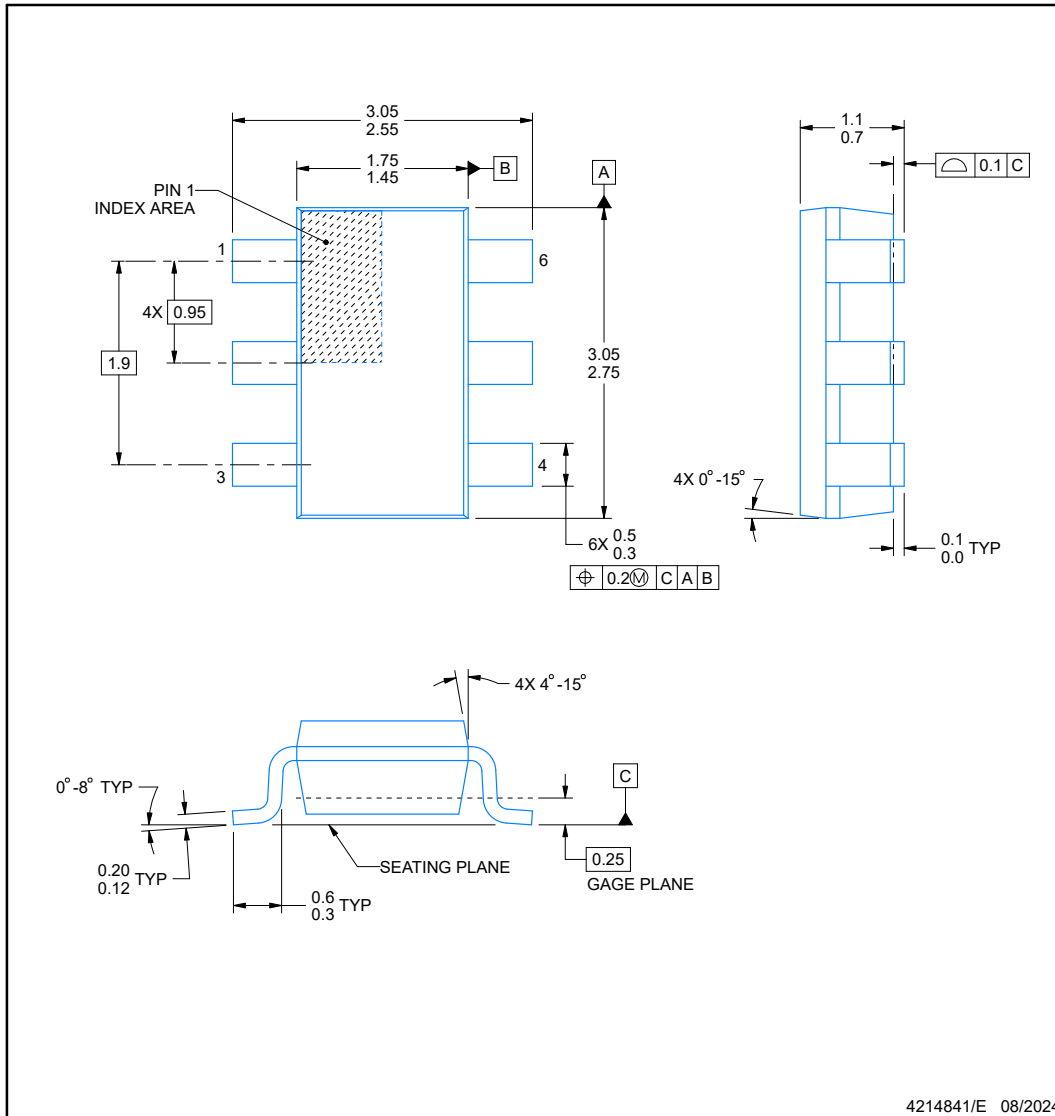
EXAMPLE BOARD LAYOUT

DDC0006A   **SOT-23 - 1.1 max height**
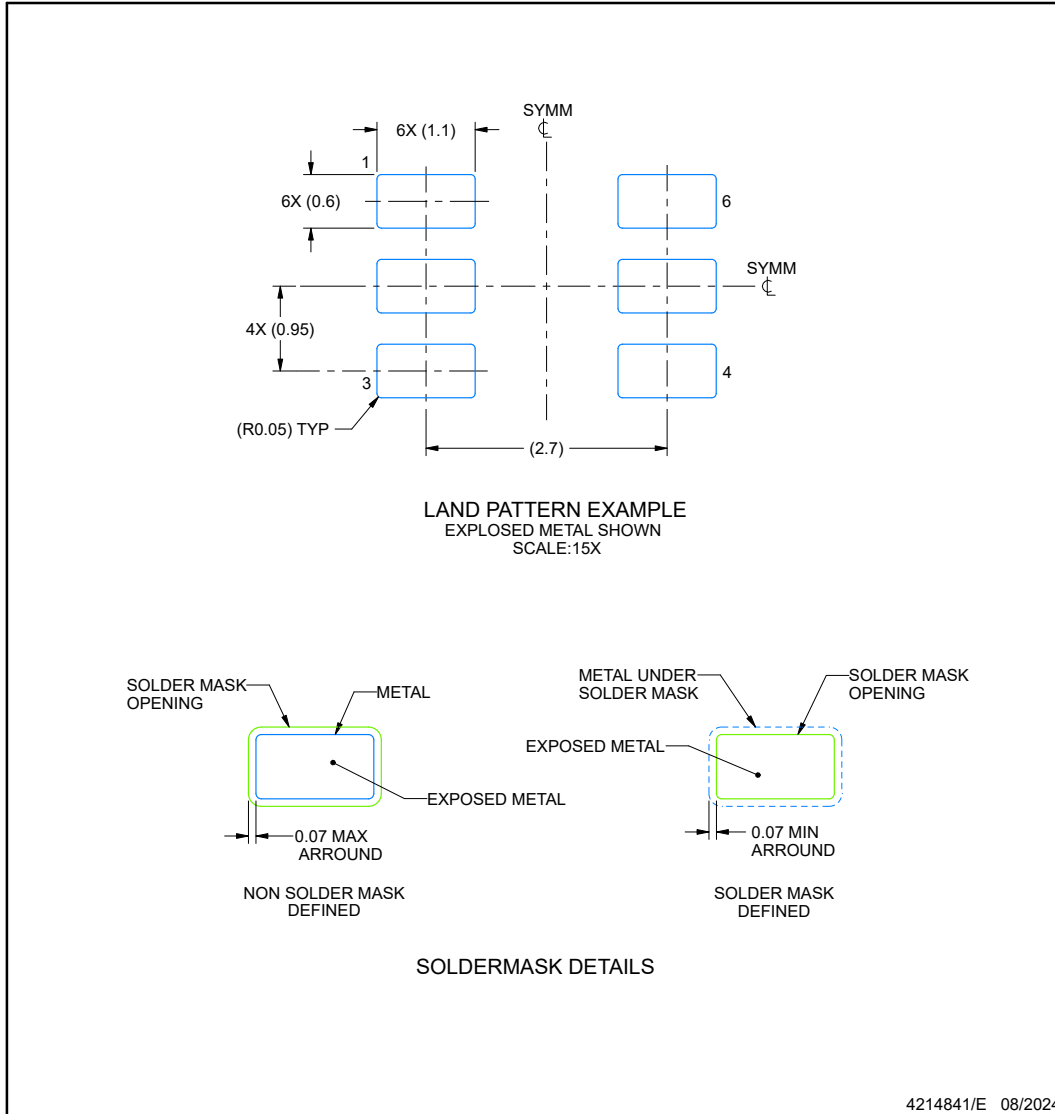
SMALL OUTLINE TRANSISTOR

6X (1.1)

1

6X (0.6)

6

SYMM

SYMM

4X (0.95)

3

4

(R0.05) TYP

(2.7)

LAND PATTERN EXAMPLE
EXPLOSED METAL SHOWN
SCALE:15X

SOLDER MASK OPENING

METAL

METAL UNDER SOLDER MASK

SOLDER MASK OPENING

EXPOSED METAL

EXPOSED METAL

0.07 MAX ARROUND

0.07 MIN ARROUND

NON SOLDER MASK DEFINED

SOLDER MASK DEFINED

SOLDERMASK DETAILS

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NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

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Product Folder Links: *TPS542021 TPS542025*

ADVANCE INFORMATION

EXAMPLE STENCIL DESIGN

DDC0006A
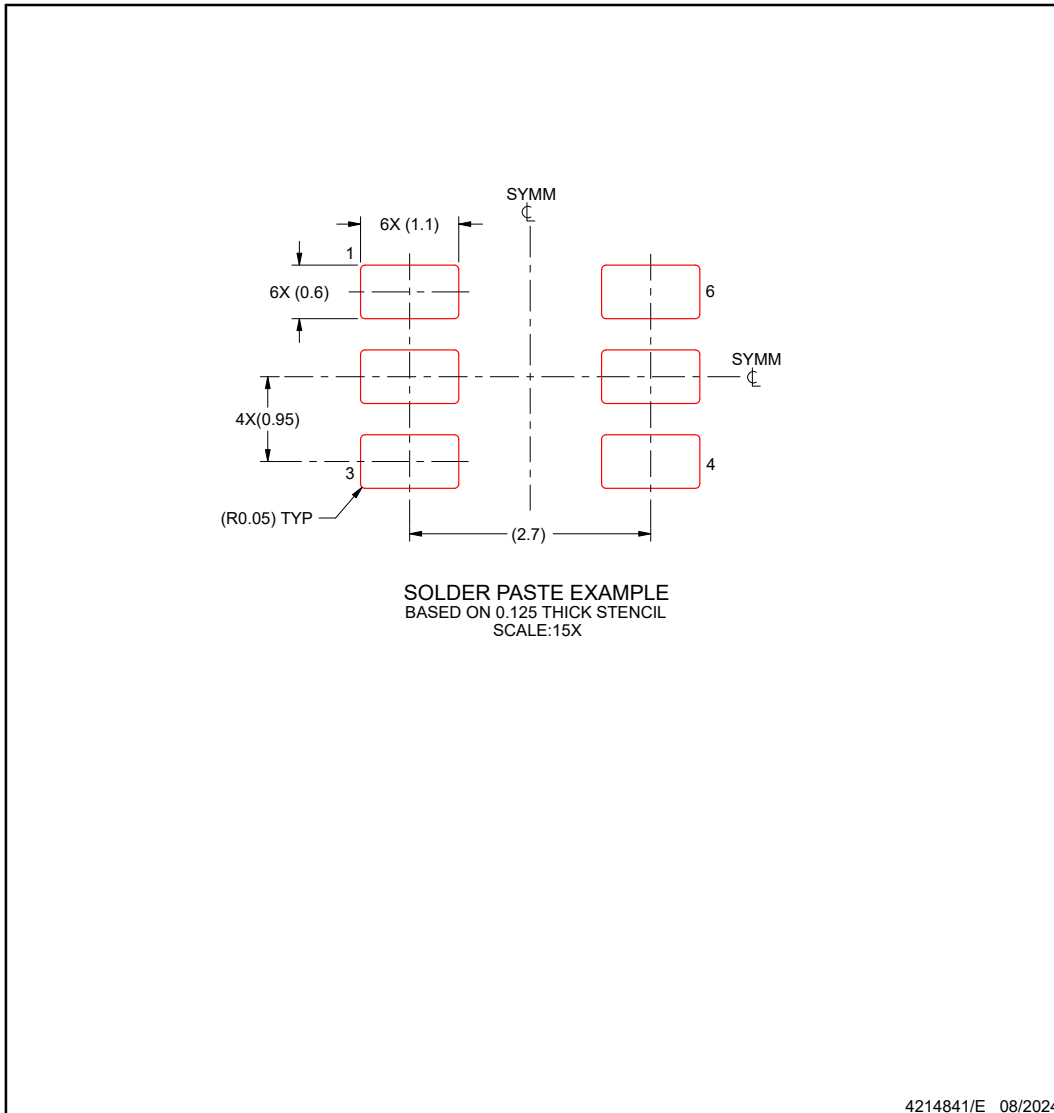
SOT-23 - 1.1 max height

SMALL OUTLINE TRANSISTOR

ADVANCE INFORMATION

SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4214841/E   08/2024

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
PTPS542021DDCR	ACTIVE	SOT-23-THIN	DDC	6	3000	TBD	Call TI	Call TI	-40 to 150		Samples
PTPS542025DDCR	ACTIVE	SOT-23-THIN	DDC	6	3000	TBD	Call TI	Call TI	-40 to 150		Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
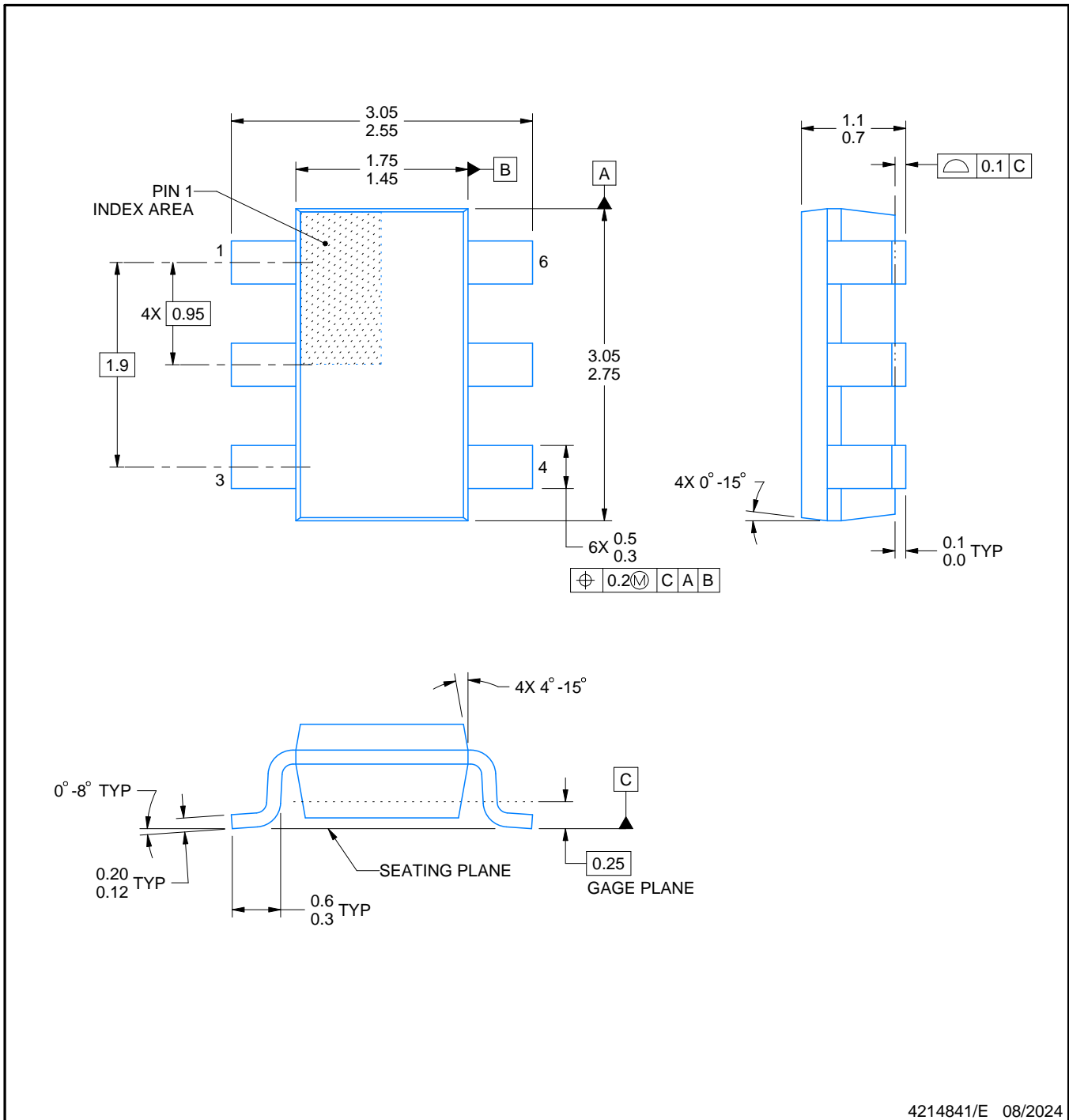
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PIN 1
INDEX AREA

3.05
2.55

1.75
1.45

B

A

1

6

4X 0.95

1.9

3.05
2.75

3

4

6X 0.5
0.3

⊕ 0.2Ⓜ C A B

1.1
0.7

⌒ 0.1 C

4X 0°-15°

0.1
0.0 TYP

4X 4°-15°

0°-8° TYP

C

0.20
0.12 TYP

SEATING PLANE

0.6
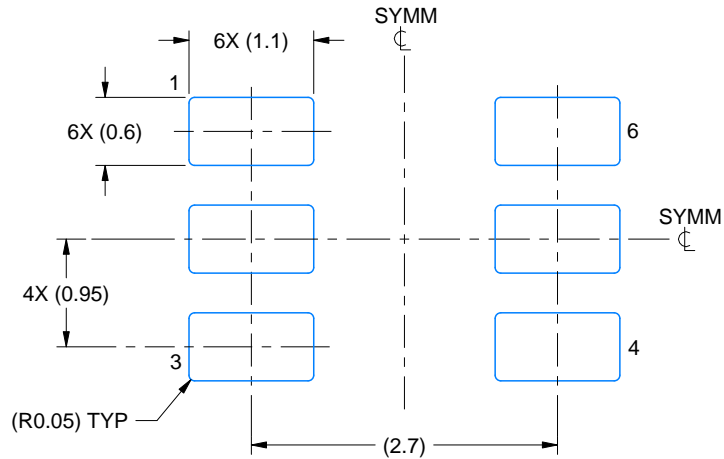0.3 TYP

0.25

GAGE PLANE

4214841/E 08/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-193.

SYMM

6X (1.1)

1

6X (0.6)

6

SYMM

4X (0.95)

3

4

(R0.05) TYP

(2.7)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.07 MAX
ARROUND

NON SOLDER MASK
DEFINED

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.07 MIN
ARROUND

SOLDER MASK
DEFINED

SOLDERMASK DETAILS

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NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

SYMM

6X (1.1)

1

6X (0.6)

SYMM

4X(0.95)

3

6

4

(R0.05) TYP

(2.7)

SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4214841/E   08/2024

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER